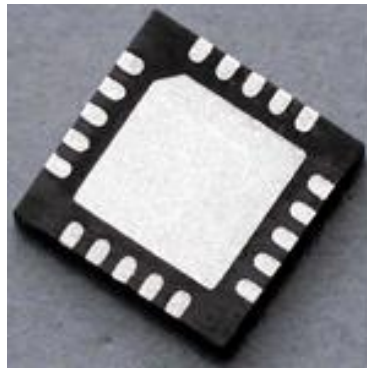


# MCF1124

MCF1124 LDO N  
 LDMOS N  
 LDMOS LDO  
 5V QFN20L



1.1 QFN20L

GATE HI LI

- N LDMOS
- $R_{DS(on)}=1.96$
- $I_{load}=500mA$
- LDO 300mA
- 3.3V/5V
- $V_{IN}+5V$
- standby 10uA
- AEC-Q100
- RoHS



/

" 11"

2) HS1 HS3

HS

HS

VCP

HI

PGND

8) CSO

CSO PGND

PGND

$V_{PGND}$

0

PGND

PGND

$V_{PGND}$

$V_{ref}$

$V_{PGND}$

$V_{ref}$

CSO

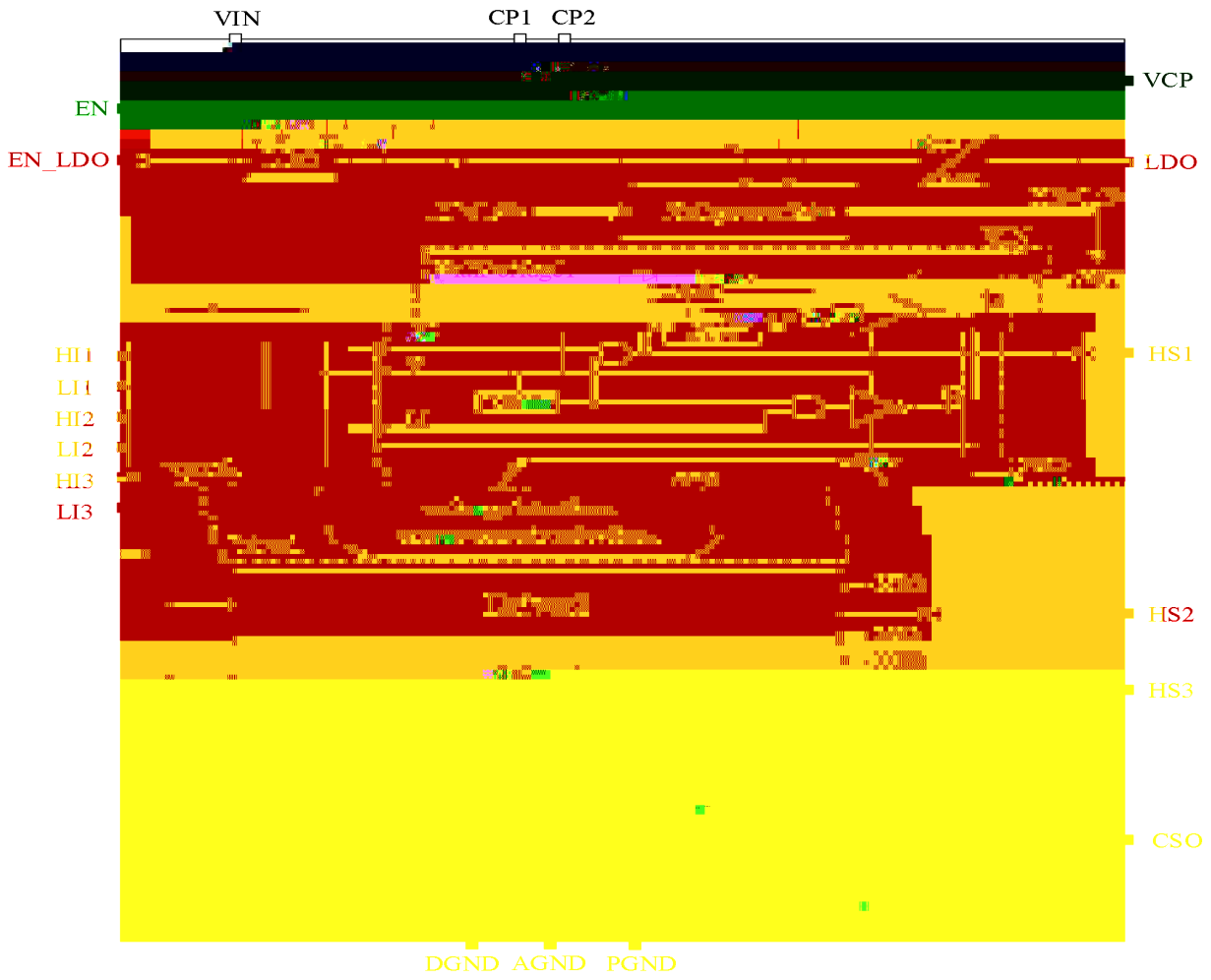
CSO

PGND

CS

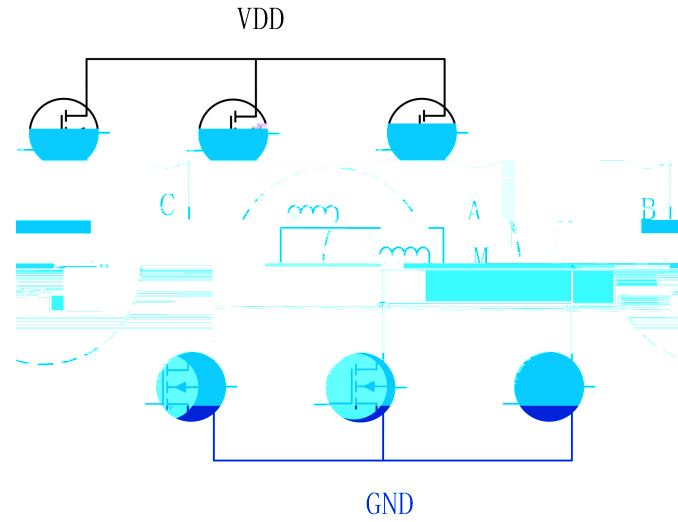
3.1

1	HS1	1
2	HS2	2
3	HS3	3
4	NC	
5	EN	standby
6	HI1	1
7	LI1	1
8	HI2	2
9	LI2	2
10	HI3	3
11	LI3	3
12	EN_LDO	VLDO VLDO 5V VLDO 3.3V
13	VLDO	3.3V/5V
14	AGND	
15	VIN	
16	CP1	
17	CP2	
18	VCP	VIN
19	PGND	1 3
20	CSO	PGND

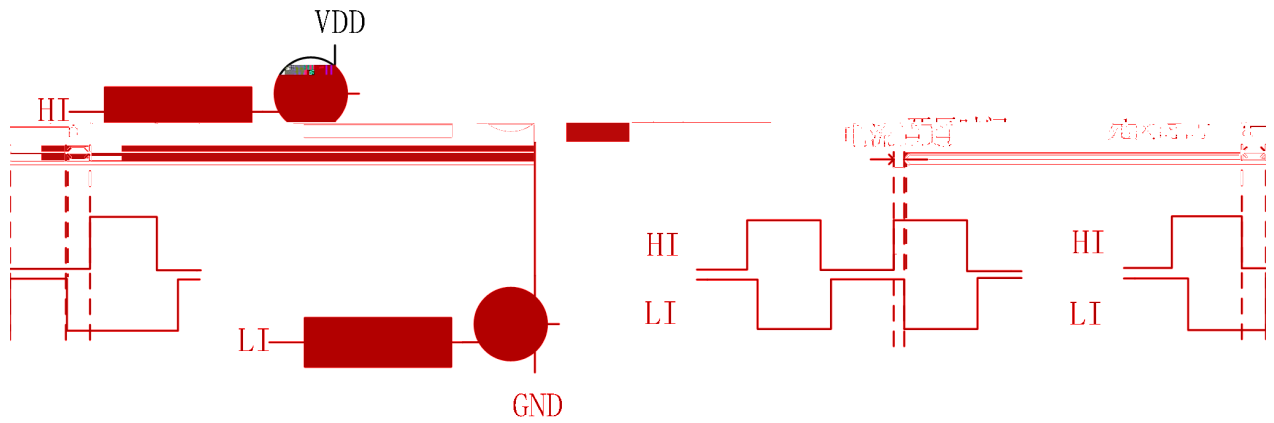


3.2





4.2



4.4  
LI

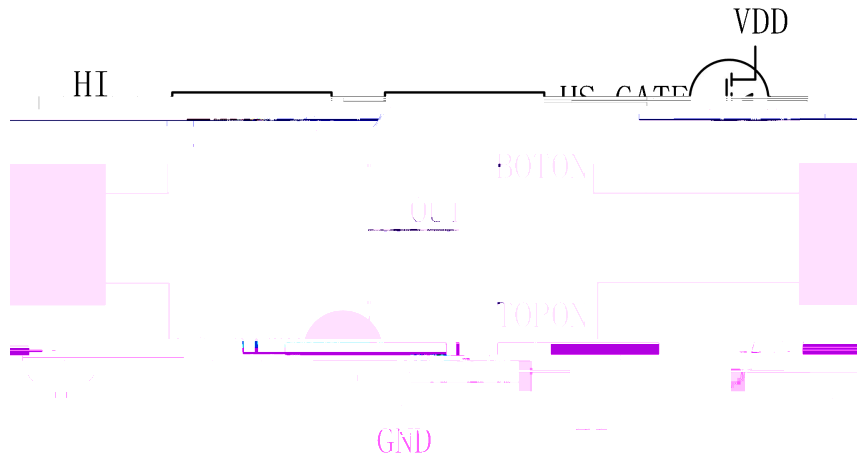
HI LI  
GND

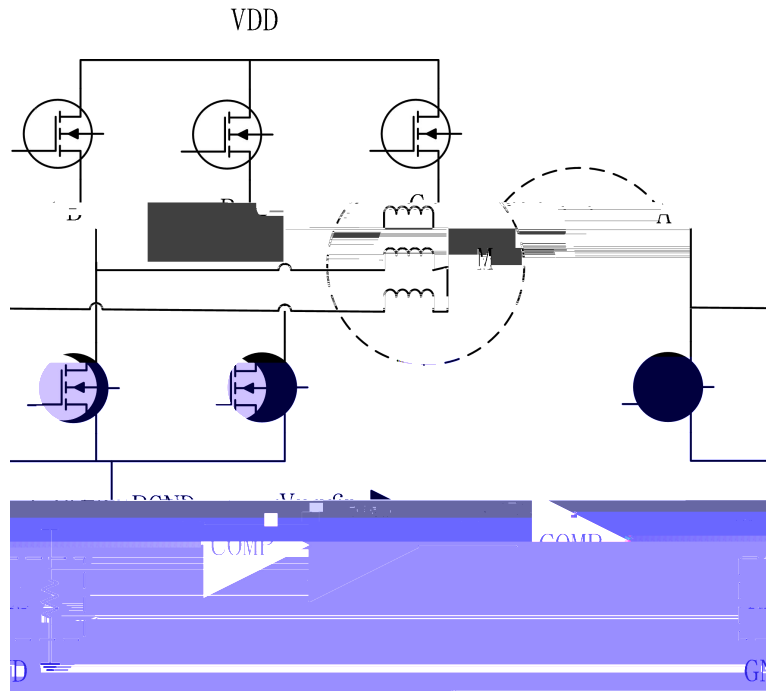
N LDMOS  
4.4b

HI  
VDD

4.4 c

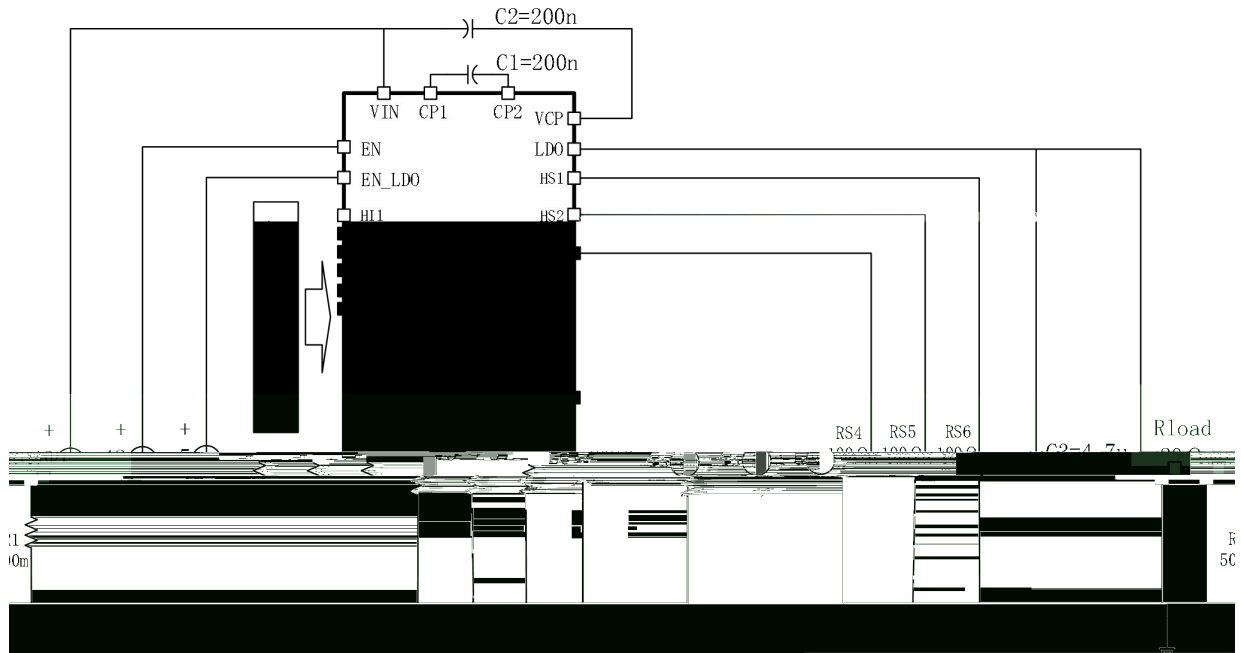
HI





4.4

N



5.1

5

$T_j = -40 \quad 150$

	VIN	-0.3	66	V	
	EN	-0.3	66	V	
	EN_LDO	-0.3	7	V	
	HI1 HI3 LI1 LI3	-0.3		V	
	HS1 HS3	0	60	V	
	VLDO	-0.3	5.5	V	

	CSO	-0.3	5.5	V	
	Tj		150		
	Tstg	-40	150		
	Rthj-a	50	90	K/W	
ESD <sup>1</sup>	V <sub>ESD-HBM</sub>	-2000	2000	V	

1) ESD

JESD22-A114

5.2

(VIN=48V

25

5.1

)

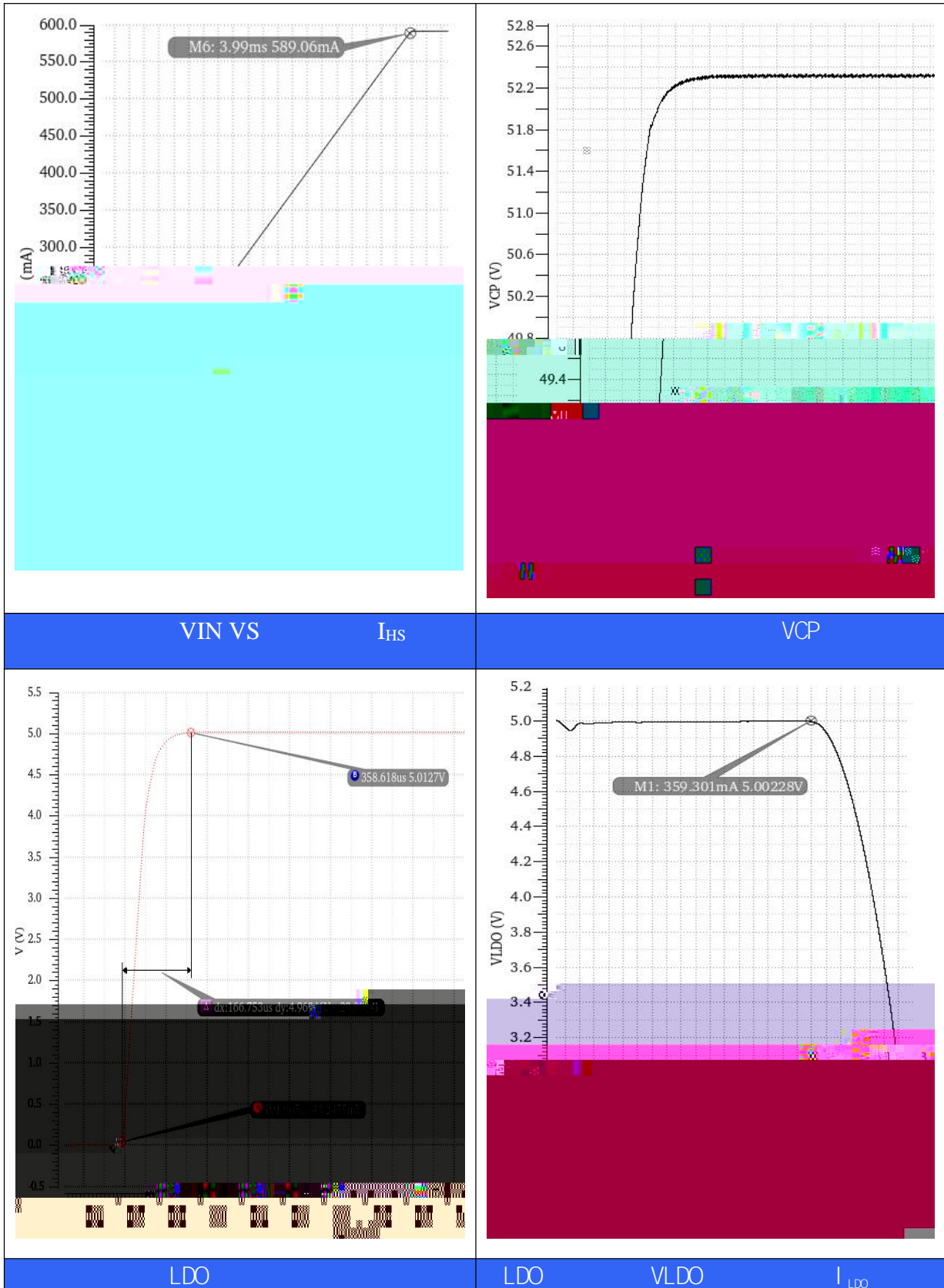
I <sub>VIN</sub>		RS1~RS3 Rload	1.74		1.92	mA
		EN=VIN				
I <sub>Q</sub>	Standby	EN=0	8.3	8.5	10	uA
I <sub>HS</sub>				472.37		mA
V <sub>HS</sub>				47.24		V
V <sub>dr</sub>	V <sub>HS</sub> V <sub>VIN</sub>	HI LI		0.76		V
R <sub>DSON_drv</sub>				1.609		

$I_{VLDO}$	LDO	EN_LDO	248.4	250.5	251.4	mA
$V_{VLDO}$	LDO			5.01		V
$R_{DSON\_LDO}$	LDO	GATE		4		
$V_{EN\_LDO}$		$V_{EN\_LDO}$ 0~5V		3.06		V
$V_{HI}/V_{LI}$		HI/LI 0~5V		3.14 1.77		V
$V_{UVLO}$		VIN 0~5V		2.92 2.74		V
$V_{OV-DET}$		VIN 0~65V		50.32 48.96		V
$V_{CP1}$		LDO	52.29 47.83	52.88 47.95		V
$V_{CP2}$			47.76 42.91	47.9 42.95		V
$V_{VCP}$			48	52.77	52.9	V
$V_{CSO}$			$V_{PGND}$ $V_{CSO}$ $V_{PGND}$		500.4 441.77	
TSD				160		
THYST				18		

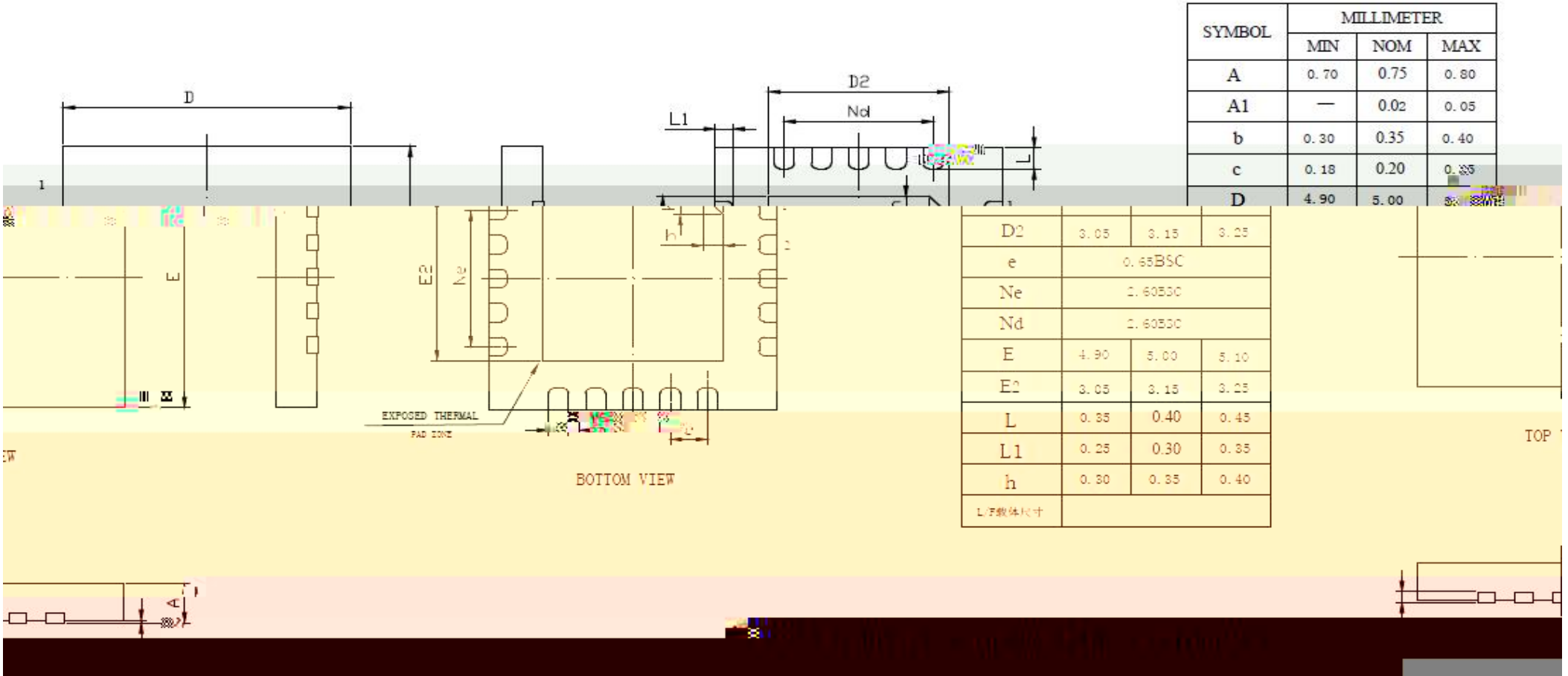
5.3

VIN=30 V TAMB = 25

5.1



MCF1124



QFN20